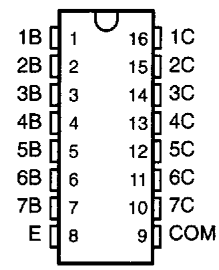
HIGH-VOLTAGE HIGH-CURRENT DARLINGTON TRANSISTOR ARRAYS

- **500-mA Rated Collector Current (Single Output)**
- **High-Voltage Outputs . . . 100 V**
- **Output Clamp Diodes**
- **Inputs Compatible With Various Types of Logic**
- **Relay Driver Applications**
- **Higher-Voltage Versions of ULN2003A and ULN2004A, for Commercial Temperature Range**

D OR N PACKAGE
(TOP VIEW)

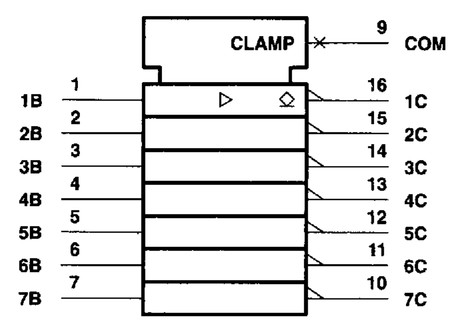


description

The SN75468 and SN75469 are monolithic high-voltage, high-current Darlington transistor arrays. Each consists of seven npn Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of each Darlington pair is 500 mA. The Darlington pairs may be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

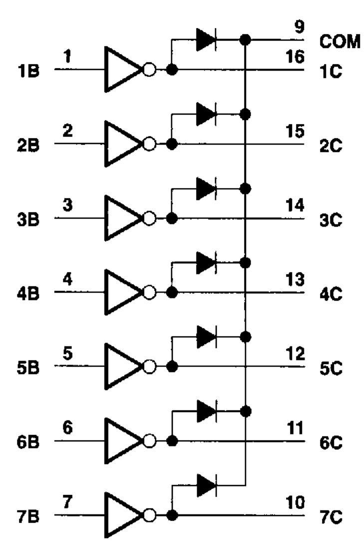
The SN75468 has a 2700-Ω series base resistor for each Darlington pair for operation directly.with TTL or 5-V CMOS. The SN75469 has a 10.5-kΩ series base resistor to allow its operation directly with CMOS or PMOS that use supply voltages of 6 to 15 V. The required input current is below that of the SN75468.

logic symbol†

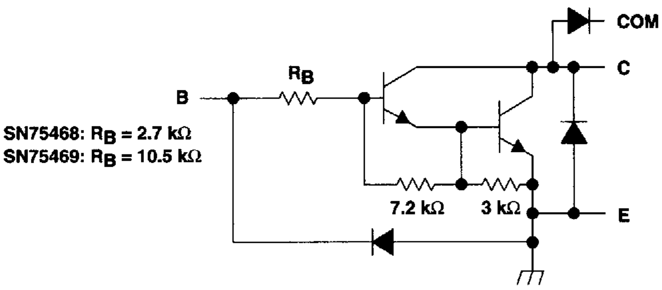


† This symbol is in accordance with ANSI/IEEE Std91-1984 and IEC publication 617-12.

logic diagram



schematic (each Darlington pair)



All resistor values shown are nominal.

absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)

Collector-emitter voltage, V_{CE}	100 V
Input voltage, V_I (see Note 1)	30 V
Peak collector current (see Figures 14 and 15)	500 mA
Output clamp current, I_{OK}	500 mA
Total emitter-terminal current	−2.5 A
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	−65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTE 1: All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25°C$ POWER RATING	DERATING FACTOR ABOVE T_A = 25°C	T_A = 70°C POWER RATING
D	950 mW	7.6 mW/°C	608 mW
N	1150 mW	9.2 mW/°C	736 mW

electrical characteristics, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST FIGURE	TEST CONDITIONS		SN75468 MIN	SN75468 TYP	SN75468 MAX	SN75469 MIN	SN75469 TYP	SN75469 MAX	UNIT
$V_{I(on)}$	On-state input voltage	5	V_{CE} = 2 V	I_C = 125 mA						5	V
				I_C = 200 mA			2.4			6	
				I_C = 250 mA			2.7				
				I_C = 275 mA						7	
				I_C = 300 mA			3				
				I_C = 350 mA						8	
$V_{CE(sat)}$	Collector-emitter saturation voltage	6	I_I = 250 µA,	I_C = 100 mA		0.9	1.1		0.9	1.1	V
			I_I = 350 µA,	I_C = 200 mA		1	1.3		1	1.3	
			I_I = 500 µA,	I_C = 350 mA		1.2	1.6		1.2	1.6	
V_F	Clamp-diode forward voltage	8	I_F = 350 mA			1.7	2		1.7	2	V
I_{CEX}	Collector cutoff current	1	V_{CE} = 100 V,	I_I = 0			50			50	µA
		1	V_{CE} = 100 V, T_A = 70°C	I_I = 0			100			100	
		2	V_{CE} = 100 V, T_A = 70°C	V_I = 1 V						500	
$I_{I(off)}$	Off-state input current	3	V_{CE} = 50 V, T_A = 70°C	I_C = 500 µA,	50	65		50	65		µA
I_I	Input current	4	V_I = 3.85 V			0.93	1.35				mA
			V_I = 5 V						0.35	0.5	
			V_I = 12 V						1	1.45	
I_R	Clamp-diode reverse current	7	V_R = 100 V				50			50	µA
			V_R = 100 V,	T_A = 70°C			100			100	
C_i	Input capacitance		V_I = 0,	f = 1 MHz		15	25		15	25	pF

switching characteristics, T_A = 25°C free-air temperature

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	V_S = 50 V, R_L = 163 Ω, C_L = 15 pF, See Figure 9		0.25	1	µs
t_{PHL}	Propagation delay time, high-to-low-level output	V_S = 50 V, R_L = 163 Ω, C_L = 15 pF, See Figure 9		0.25	1	µs
V_{OH}	High-level output voltage after switching	V_S = 50 V, I_O ≈ 300 mA, See Figure 10	V_S−20			mV

PARAMETER MEASUREMENT INFORMATION

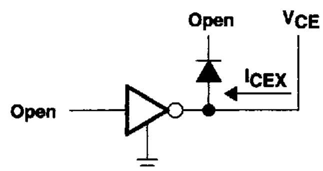


Figure 1. I_{CEX}

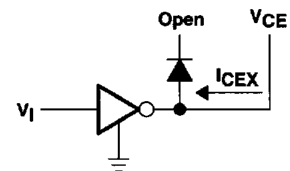


Figure 2. I_{CEX}

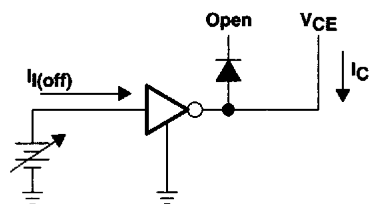


Figure 3. $I_{I(off)}$

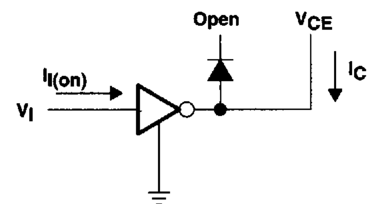


Figure 4. I_I

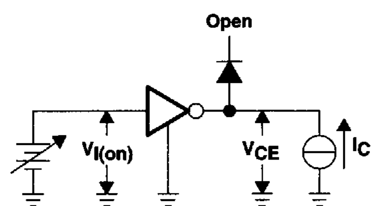
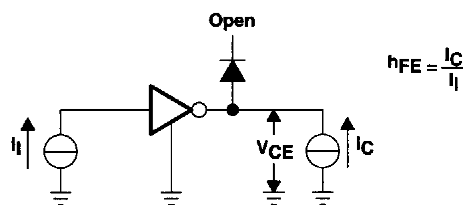


Figure 5. $V_{I(on)}$



NOTE: I_I is fixed for measuring $V_{CE(sat)}$, variable for measuring h_{FE}.

Figure 6. h_{FE}, $V_{CE(sat)}$

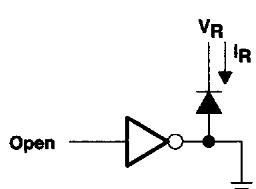


Figure 7. I_R

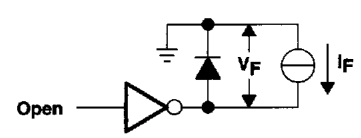


Figure 8. V_F

PARAMETER MEASUREMENT INFORMATION

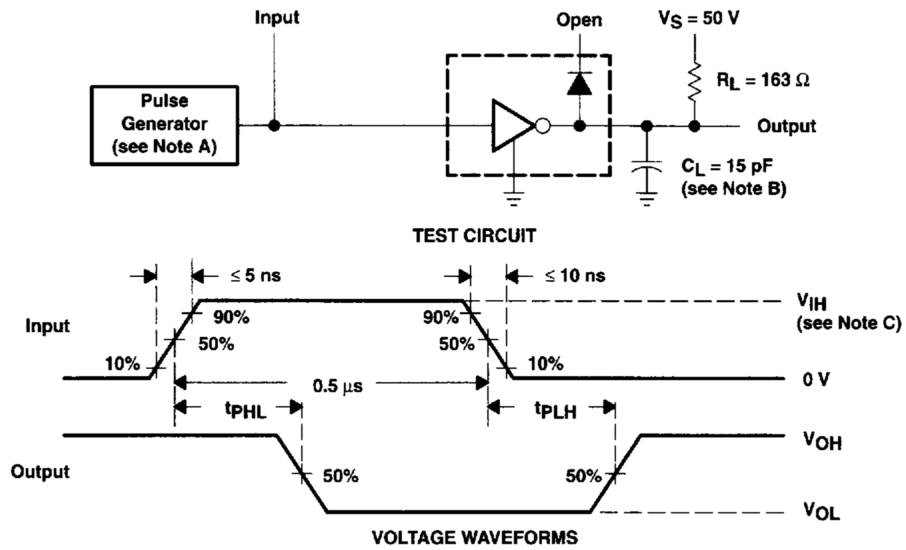


Figure 9. Test Circuit and Voltage Waveforms

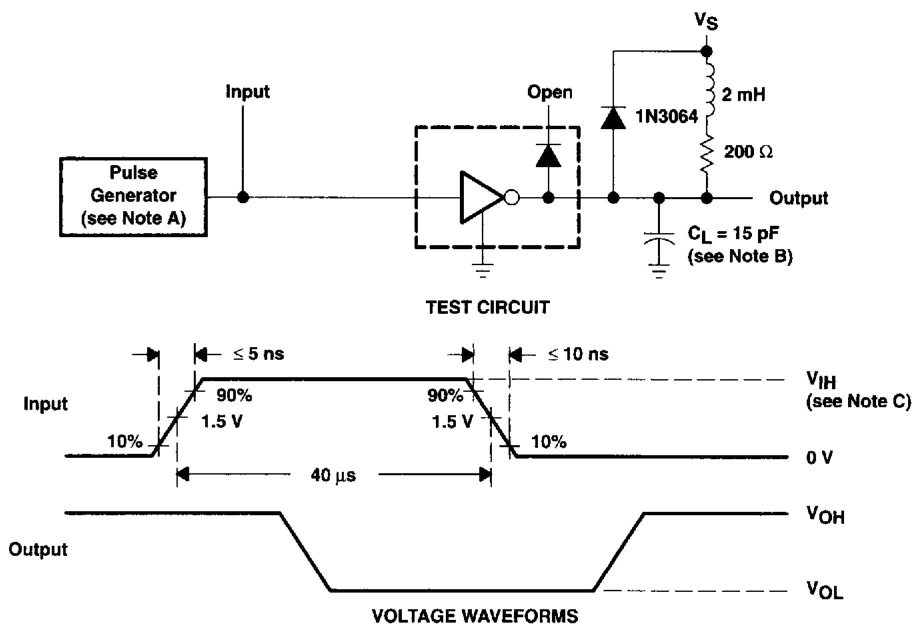


Figure 10. Latch-Up Test Circuit and Voltage Waveforms

NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.
C. For testing the '468, V_{IH} = 3 V; for the '469, V_{IH} = 8 V.

TYPICAL CHARACTERISTICS

COLLECTOR-EMITTER SATURATION VOLTAGE vs COLLECTOR CURRENT (ONE DARLINGTON)

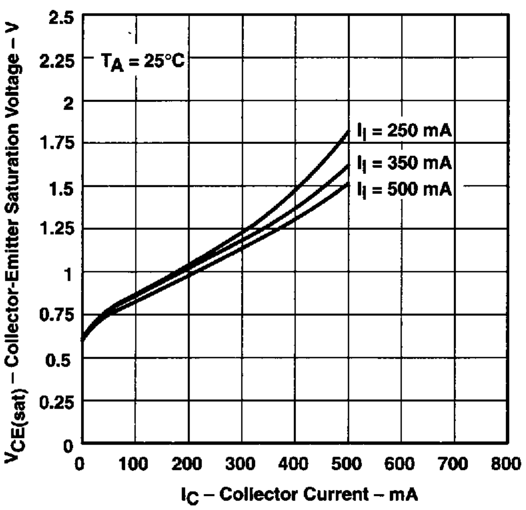


Figure 11

COLLECTOR-EMITTER SATURATION VOLTAGE vs COLLECTOR CURRENT (TWO DARLINGTONS PARALLELED)

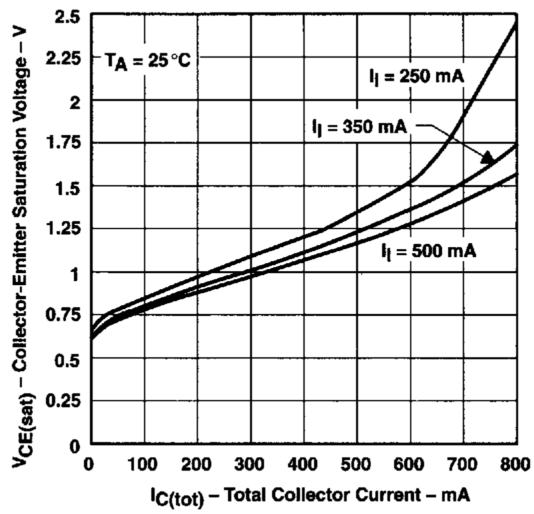


Figure 12

COLLECTOR CURRENT vs INPUT CURRENT

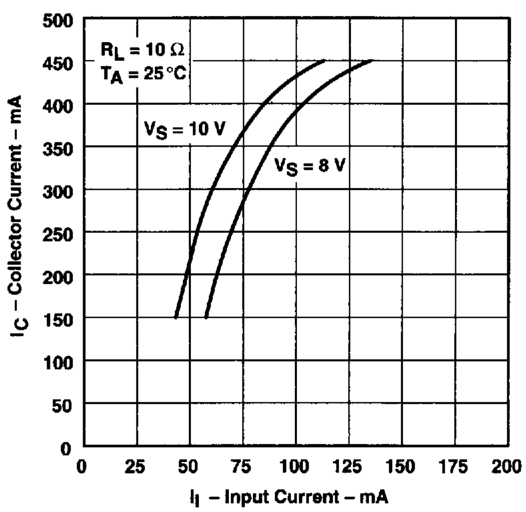


Figure 13

THERMAL INFORMATION

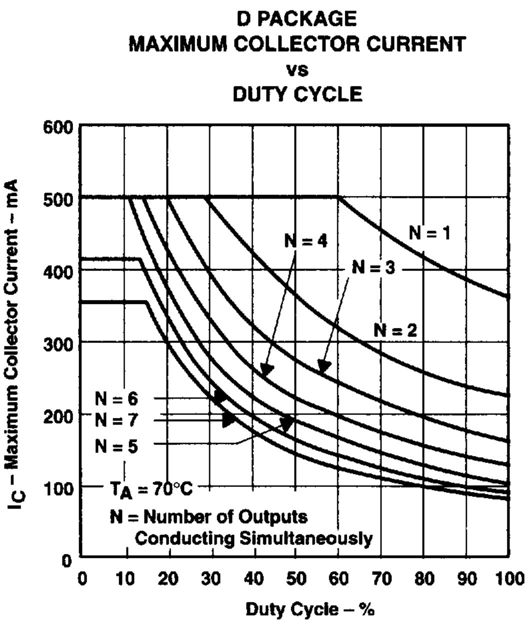


Figure 14

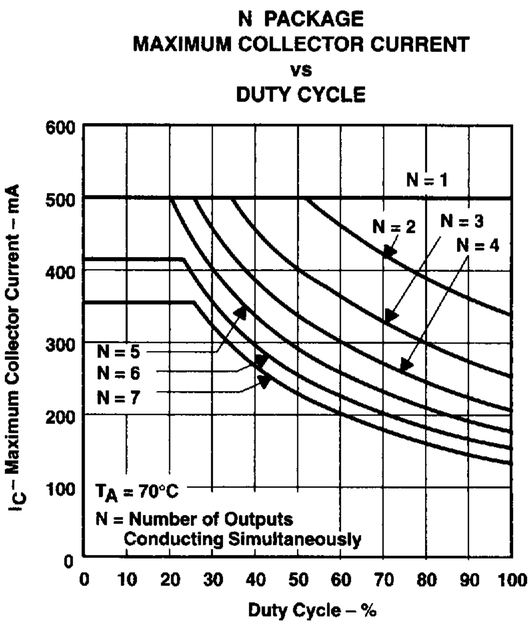


Figure 15

APPLICATION INFORMATION

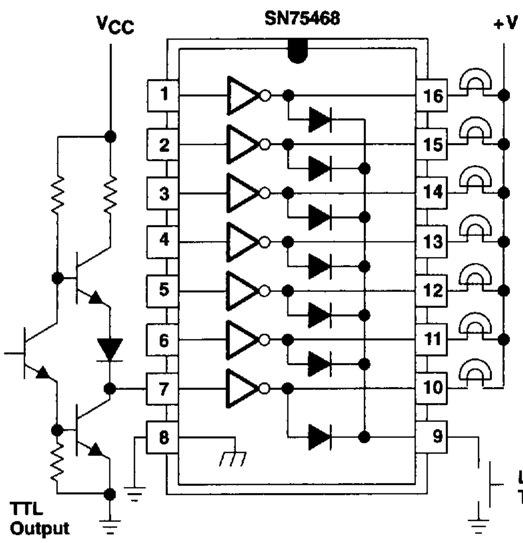


Figure 16. TTL to Load

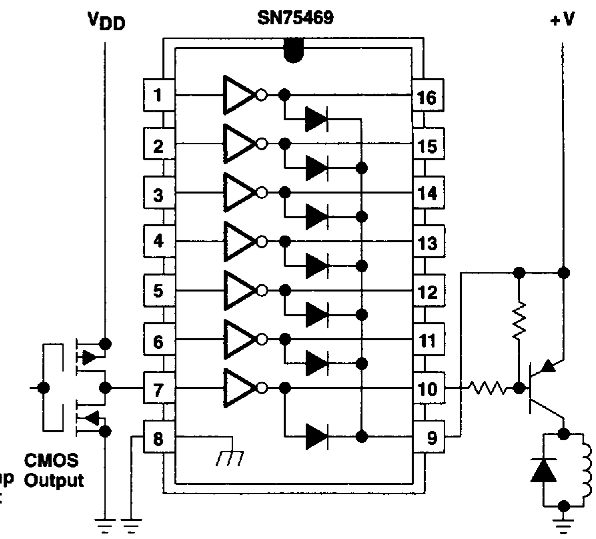


Figure 17. Buffer for Higher Current Loads

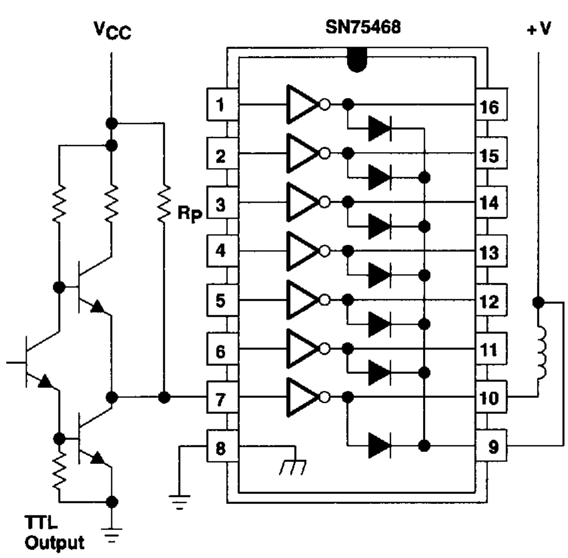


Figure 18. Use of Pullup Resistors to Increase Drive Current